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Renesas Electronics website: http://www.renesas.com

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Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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# 2SK2144 Silicon N Channel MOS FET

REJ03G1001-0200 (Previous: ADE-208-1349) Rev.2.00 Sep 07,2005

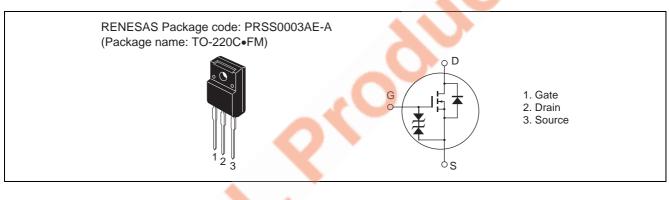
### Application

High speed power switching

### Features

- Low on-resistance
- High speed switching
- Low drive current
- No Secondary Breakdown
- Suitable for switching regulator, DC-DC converter

### Outline





# Absolute Maximum Ratings

|   |                                      |             | (Ta = 25°C) |
|---|--------------------------------------|-------------|-------------|
| Item                                      | Symbol                               | Ratings     | Unit        |
| Drain to source voltage                   | V <sub>DSS</sub>                     | 600         | V           |
| Gate to source voltage                    | V <sub>GSS</sub>                     | ±30         | V           |
| Drain current                             | ID                                   | 3           | A           |
| Drain peak current                        | I <sub>D(pulse)</sub> * <sup>1</sup> | 6           | A           |
| Body to drain diode reverse drain current | I <sub>DR</sub>                      | 3           | A           |
| Channel dissipation                       | Pch* <sup>2</sup>                    | 25          | W           |
| Channel temperature                       | Tch                                  | 150         | °C          |
| Storage temperature                       | Tstg                                 | -55 to +150 | °C          |

Notes: 1.  $PW \le 10 \ \mu s$ , duty cycle  $\le 1 \ \%$ 

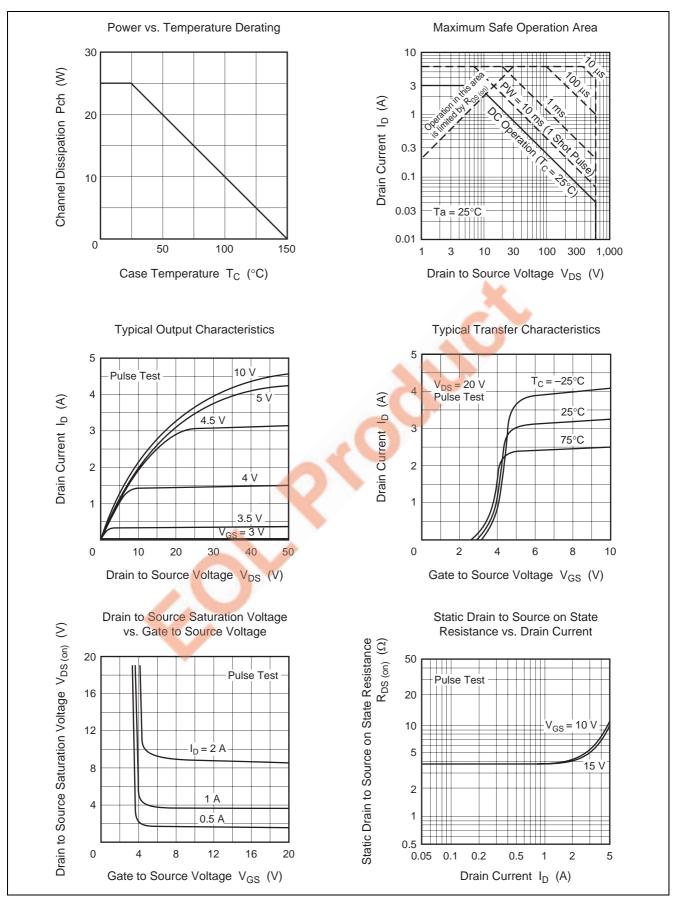
2. Value at  $Tc = 25^{\circ}C$ 

# **Electrical Characteristics**

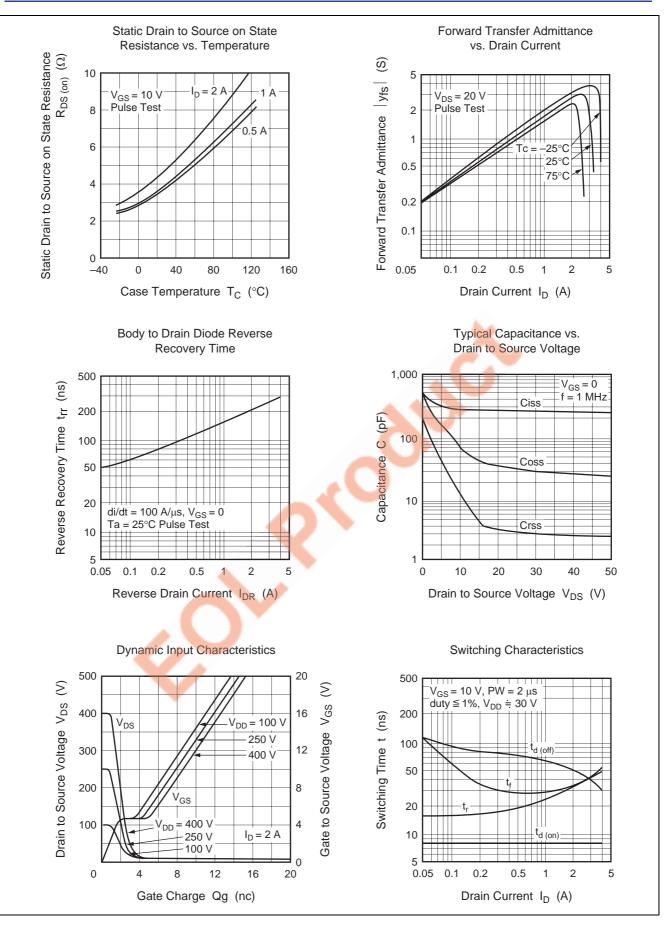
|  |                      |     |     |     |      | $(Ta = 25^{\circ}C)$  |
|--|----------------------|-----|-----|-----|------|---|
| ltem                                       | Symbol               | Min | Тур | Max | Unit | Test conditions   |
| Drain to source breakdown voltage          | V <sub>(BR)DSS</sub> | 600 | —   | —   | V    | $I_{D} = 10 \text{ mA}, V_{GS} = 0$   |
| Gate to source breakdown voltage           | V <sub>(BR)GSS</sub> | ±30 | —   | —   | V    | $I_{G} = \pm 100 \ \mu A, V_{DS} = 0$   |
| Gate to source leak current                | I <sub>GSS</sub>     | —   | —   | ±10 | μA   | $V_{GS} = \pm 25 \text{ V}, V_{DS} = 0$   |
| Zero gate voltage drain current            | I <sub>DSS</sub>     | _   | —   | 250 | μA   | $V_{DS} = 500 \text{ V}, V_{GS} = 0$  |
| Gate to source cutoff voltage              | V <sub>GS(off)</sub> | 2.0 | —   | 3.0 | V    | $I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$   |
| Static drain to Source on state resistance | R <sub>DS(on)</sub>  | _   | 3.8 | 5.0 | Ω    | $I_D = 1 \text{ A}, V_{GS} = 10 \text{ V}^{*3}$   |
| Forward transfer admittance                | y <sub>fs</sub>      | 1.2 | 2.0 | ) — | S    | $I_D = 1 \text{ A}, V_{DS} = 10 \text{ V}^{*3}$   |
| Input capacitance                          | Ciss                 |     | 295 | _   | pF   | $V_{DS} = 10 V, V_{GS} = 0,$  |
| Output capacitance                         | Coss                 |     | 70  | —   | pF   | f = 1 MHz   |
| Reverse transfer capacitance               | Crss                 |     | 12  | —   | pF   |   |
| Turn-on delay time                         | t <sub>d(on)</sub>   |     | 8   | —   | ns   | $I_{D} = 1 \text{ A}, \text{ V}_{\text{GS}} = 10 \text{ V},$ $R_{\text{L}} = 30 \Omega$ |
| Rise time                                  | tn                   | _   | 25  | —   | ns   |   |
| Turn-off delay time                        | t <sub>d(off)</sub>  |     | 65  | —   | ns   |   |
| Fall time                                  | tr                   | -   | 30  | —   | ns   |   |
| Body to drain diode forward voltage        | Vdf                  | _   | 0.9 | _   | V    | $I_F = 2 A, V_{GS} = 0$   |
| Body to drain diode reverse recovery time  | trr                  |     | 220 | _   | ns   | $I_F = 2 A, V_{GS} = 0,$<br>$di_F / dt = 100 A / \mu s$                                 |
| Note: 3. Pulse Test                        |                      | -   | -   |     | -    |   |



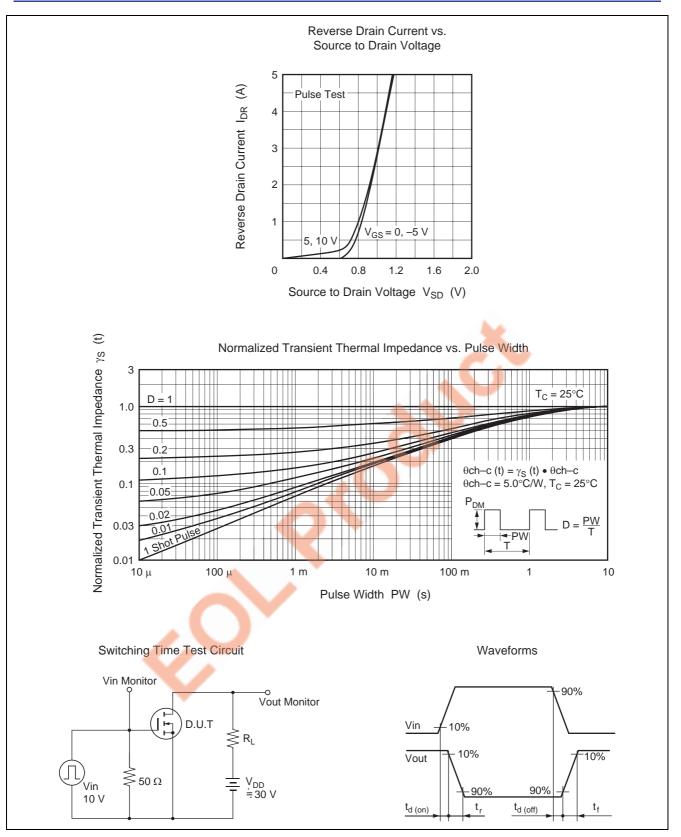
### **Main Characteristics**



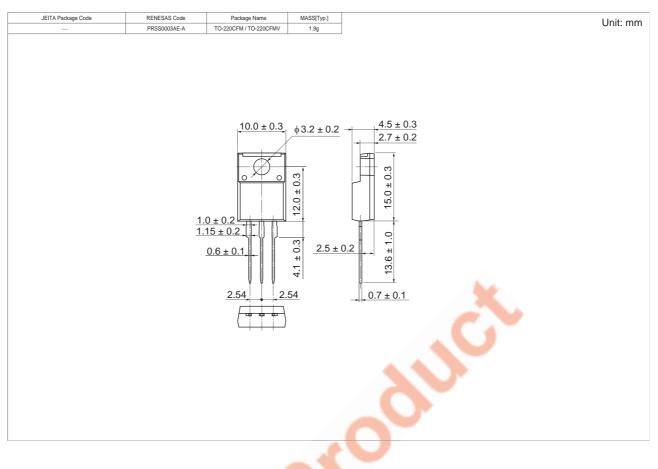








### **Package Dimensions**



### **Ordering Information**

| Part Name | Quantity | Shipping Container |
|-----------|----------|--------------------|
| 2SK2144-E | 600 pcs  | Box (Tube)         |

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.



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